

Description

The VSM60N08 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. This device is suitable for use in PWM, load switching and general purpose applications.

General Features

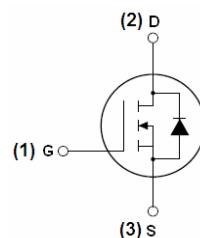
- $V_{DS} = 80V, I_D = 60A$
- $R_{DS(ON)} < 12 \text{ m}\Omega @ V_{GS}=10V$ (Typ:9mΩ)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Special designed for converters and power controls
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard switched and High frequency circuits
- Uninterruptible power supply



TO-252



Schematic Diagram

Package Marking and Ordering Information

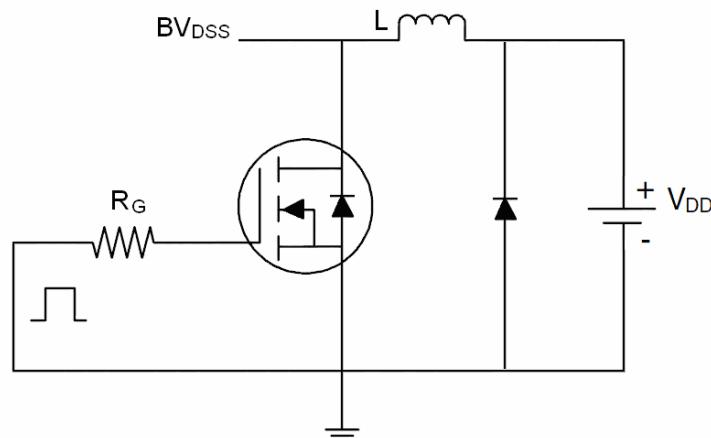
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
VSM60N08-T2	VSM60N08	TO-252	-	-	-

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

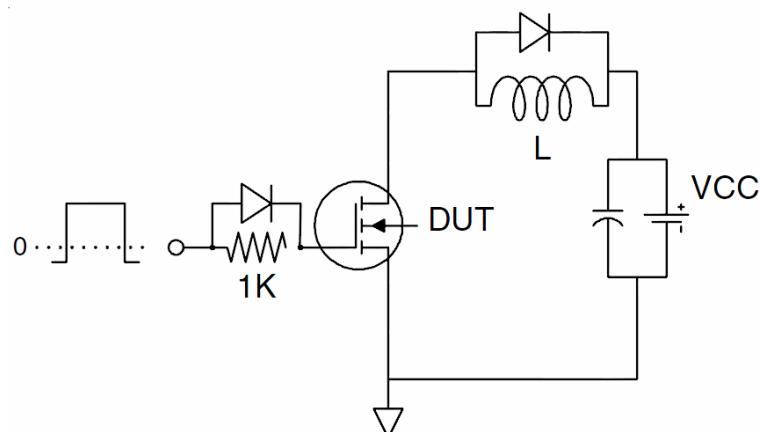
Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	80	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous	I_D	60	A
Drain Current-Continuous($T_C=100^\circ\text{C}$)	$I_D (100^\circ\text{C})$	42.4	A
Pulsed Drain Current ^(Note 1)	I_{DM}	240	A
Maximum Power Dissipation	P_D	130	W
Derating factor		0.87	W/°C
Single pulse avalanche energy ^(Note 5)	E_{AS}	380	mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 175	°C

Test Circuit

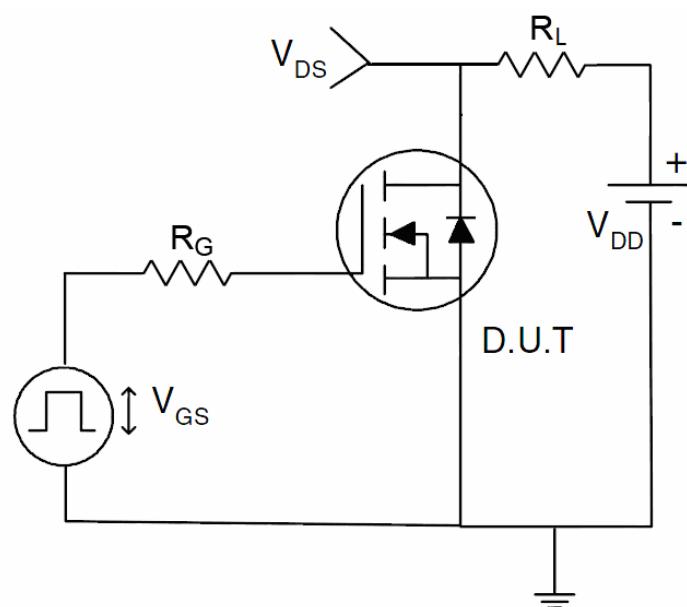
1) E_{AS} Test Circuits



2) Gate Charge Test Circuit



3) Switch Time Test Circuit



Typical Electrical and Thermal Characteristics (Curves)

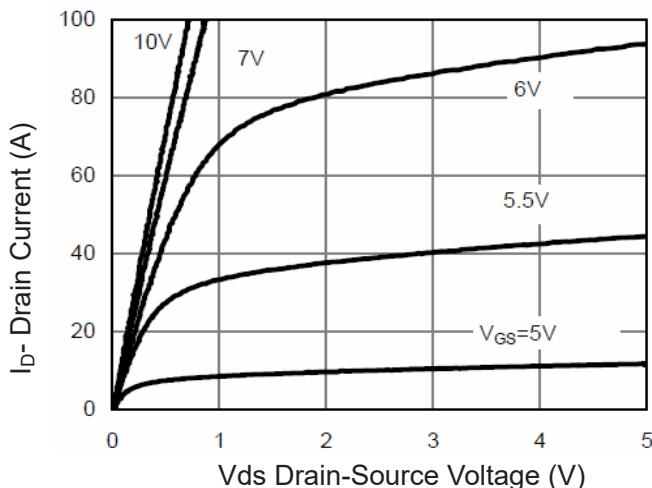


Figure 1 Output Characteristics

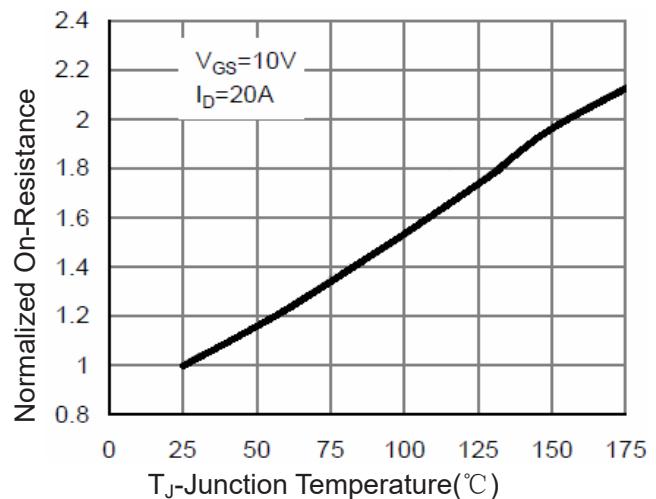


Figure 4 Rdson-Junction Temperature

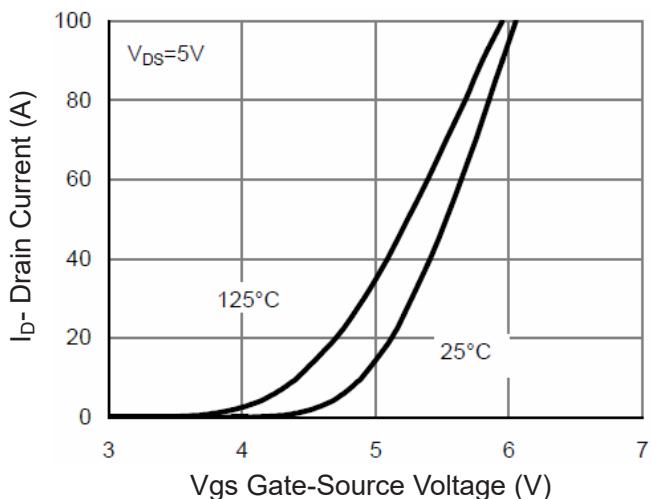


Figure 2 Transfer Characteristics

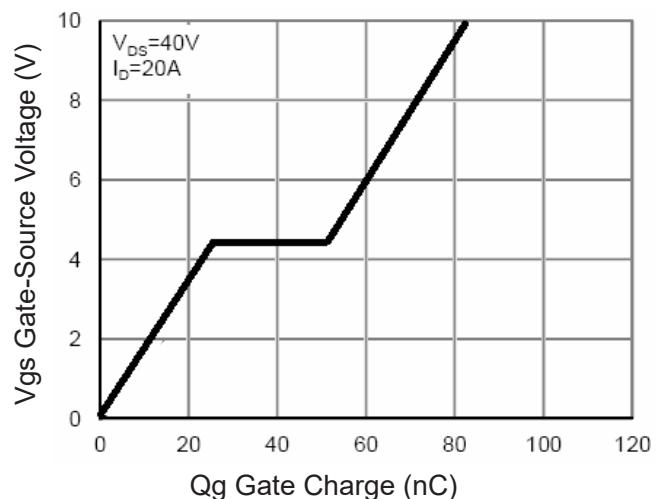


Figure 5 Gate Charge

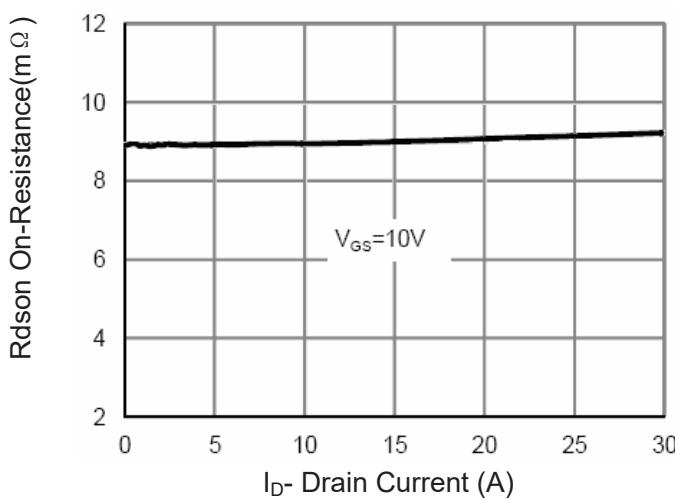


Figure 3 Rdson- Drain Current

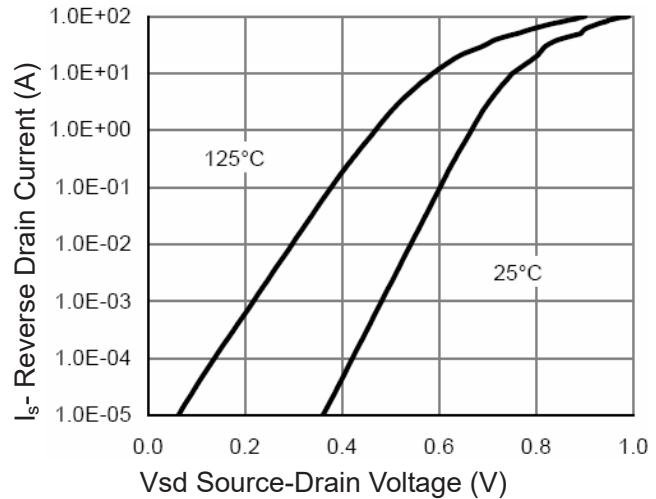
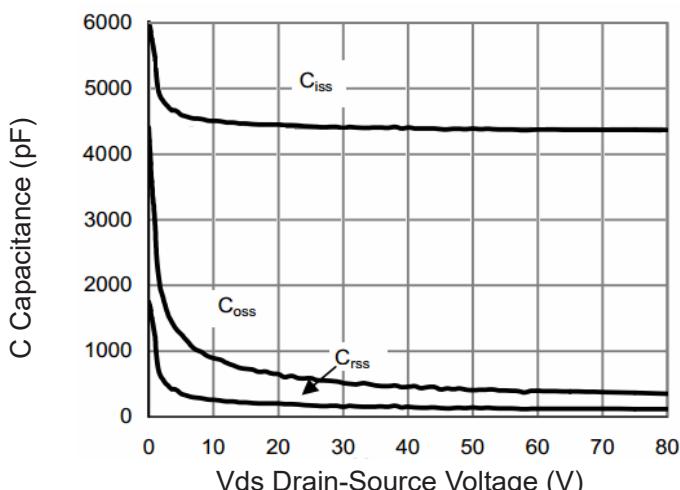
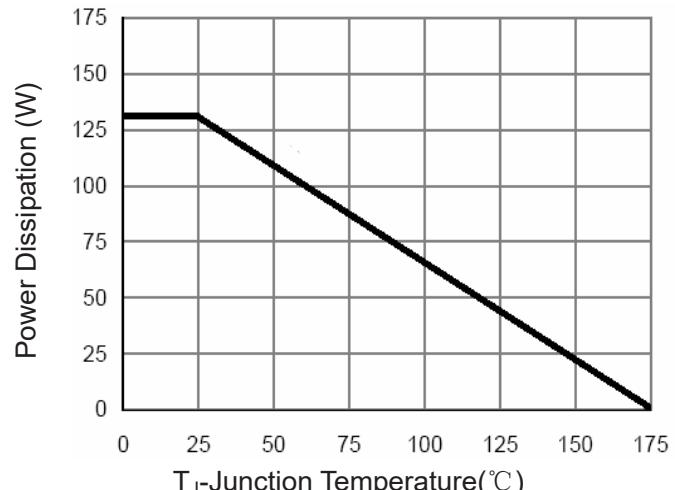
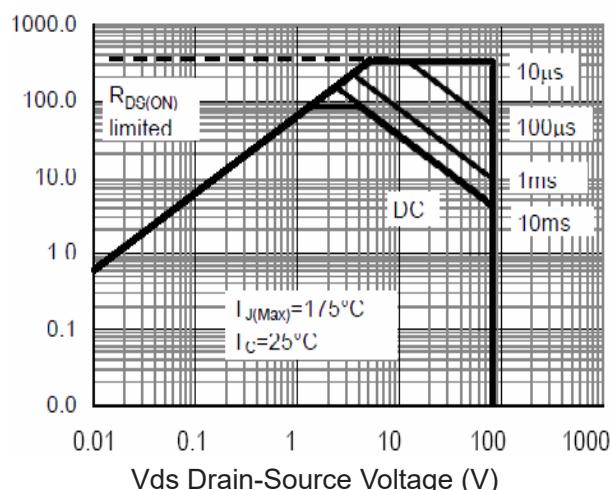
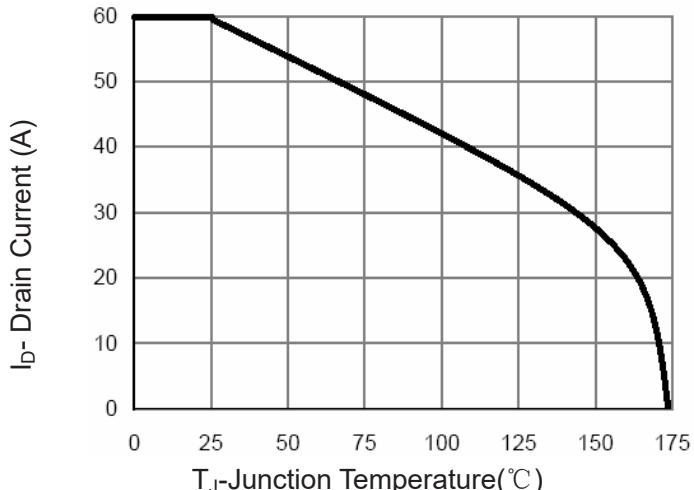
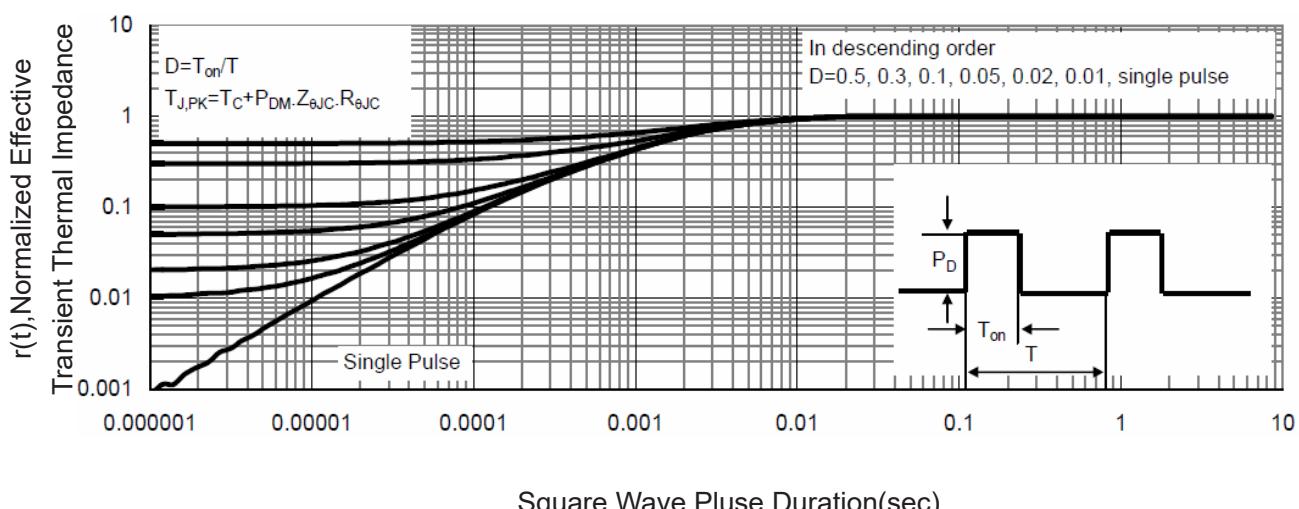


Figure 6 Source- Drain Diode Forward


Figure 7 Capacitance vs Vds

Figure 9 Power De-rating

Figure 8 Safe Operation Area

Figure 10 I_D Current De-rating

Figure 11 Normalized Maximum Transient Thermal Impedance